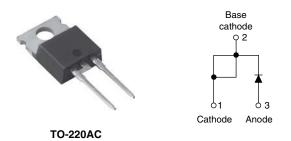
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Ultrafast Rectifier, 8 A FRED Pt[®]



PRODUCT SUMMARY								
Package	TO-220AC							
I _{F(AV)}	8 A							
V _R	200 V							
V _F at I _F	0.975 V							
t _{rr} typ.	See Recovery table							
T _J max.	175 °C							
Diode variation	Single die							

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION/APPLICATIONS

VS-MUR820PbF is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Peak repetitive reverse voltage	V _{RRM}		200	V						
Average rectified forward current	I _{F(AV)}	Total device, rated V _R , T _C = 150 °C	8							
Non-repetitive peak surge current	I _{FSM}		100	А						
Peak repetitive forward current		Rated V _R , square wave, 20 kHz, T _C = 150 °C	16							
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C						

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-				
Forward voltage	V _F	I _F = 8 A	0.97		0.975	V			
		I _F = 8 A, T _J = 150 °C	-	-	0.895				
Reverse leakage current	I _R	$V_R = V_R$ rated	-	-	5				
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ -		-	250	μA			
Junction capacitance	CT	V _R = 200 V	-	25	-	pF			
Series inductance	Ls	Measured lead to lead 5 mm from package body	-	8.0	-	nH			

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RoHS

COMPLIANT

HALOGEN

FREE

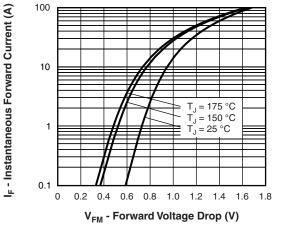


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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	50 A/µs, V _R = 30 V	-	-	35				
	t _{rr}	I _F = 0.5 A, I _R = 1.0	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{REC} = 0.25 \text{ A}$			25	ns			
		T _J = 25 °C		-	20	-	115			
		T _J = 125 °C	I _F = 8 A dI _F /dt = 200 A/µs	-	34	-				
Peak recovery current	I _{RRM}	T _J = 25 °C		-	1.7	-	А			
		T _J = 125 °C	$V_{\rm R} = 160 {\rm V}$	-	4.2	-	A			
Reverse recovery charge	0	T _J = 25 °C		-	23	-				
	Q _{rr}	T _J = 125 °C		-	75	-	nC			

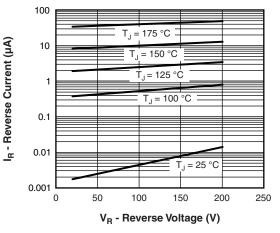
THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C				
Thermal resistance, junction to case	R _{thJC}		-	-	3.0					
Thermal resistance, junction to ambient	R _{thJA}		-	-	50	°C/W				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-					
Weight			-	2.0	-	g				
weight			-	0.07	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style TO-220AC		MUF	R820					

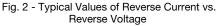
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Fig. 1 - Maximum Forward Voltage Drop Characteristics





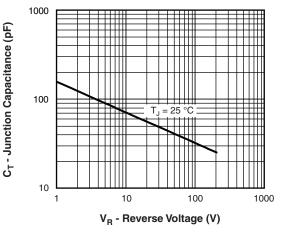


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

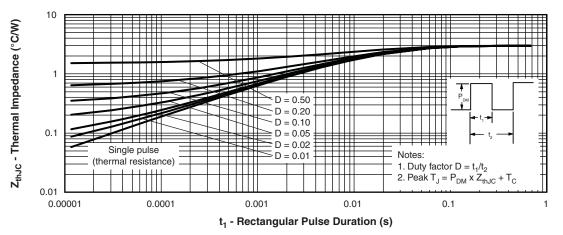
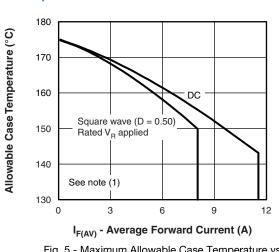
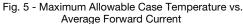


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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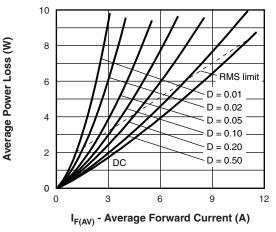
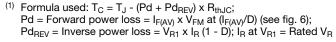
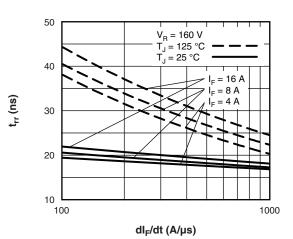


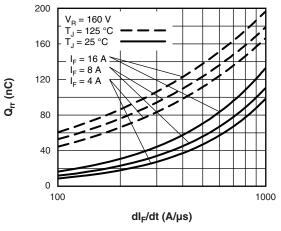
Fig. 6 - Forward Power Loss Characteristics

Note











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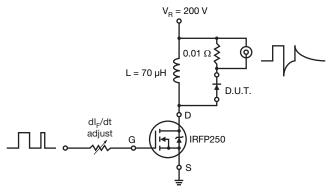


Fig. 9 - Reverse Recovery Parameter Test Circuit

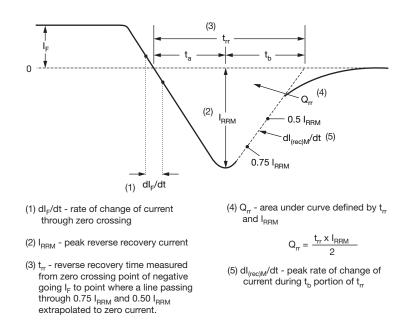


Fig. 10 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code	VS-	MUR	8	20	PbF	
		2	3	4	5	l
	1 - 2 -		nay Sem afast MU			oduct
	3 -	Curi	rent ratir	ng (8 = 8	3 A)	
	4 -		age ratii	•	,	
	5 -		ironmen = Lead	0		RoHS compliant
				. ,		

-N3 = Halogen-free, RoHS compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MUR820PbF	50	1000	Antistatic plastic tube					
VS-MUR820-N3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS								
Dimensions		www.vishay.com/doc?95221						
	TO-220ACPbF	www.vishay.com/doc?95224						
Part marking information	TO-220AC-N3	www.vishay.com/doc?95068						



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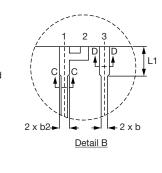
TO-220AC

plane

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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